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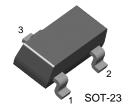
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### **KST5550**

### **High Voltage Transistor**



1. Base 2. Emitter 3. Collector

## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** T<sub>a</sub>=25°C unless otherwise noted

| Symbol           | Parameter                     | Value | Units |
|------------------|-------------------------------|-------|-------|
| $V_{CBO}$        | Collector-Base Voltage        | 160   | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage 140 |       | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage          | 6     | V     |
| I <sub>C</sub>   | Collector Current             | 600   | mA    |
| P <sub>C</sub>   | Collector Power Dissipation   | 350   | mW    |
| T <sub>STG</sub> | Storage Temperature           | 150   | °C    |

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

| Symbol                | Parameter                            | Test Condition   | Min.           | Max.         | Units  |
|-----------------------|--------------------------------------|--|----------------|--------------|--------|
| BV <sub>CBO</sub>     | Collector-Base Breakdown Voltage     | I <sub>C</sub> =10μA, I <sub>E</sub> =0  | 160            |              | V      |
| BV <sub>CEO</sub>     | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> =1mA, I <sub>B</sub> =0   | 140            |              | V      |
| BV <sub>EBO</sub>     | Emitter-Base Breakdown Voltage       | I <sub>E</sub> =10μA, I <sub>C</sub> =0  | 6              |              | V      |
| I <sub>CBO</sub>      | Collector Cut-off Current            | V <sub>CB</sub> =100V, I <sub>E</sub> =0   |                | 100          | nA     |
| I <sub>EBO</sub>      | Emitter Cut-off Current              | V <sub>EB</sub> =4V, I <sub>C</sub> =0   |                | 50           | nA     |
| h <sub>FE</sub>       | DC Current Gain                      | $V_{CE}$ =5V, $I_{C}$ =1.0mA<br>$V_{CE}$ =5V, $I_{C}$ =10mA<br>$V_{CE}$ =5V, $I_{C}$ =50mA | 60<br>60<br>20 | 250          |        |
| V <sub>CE</sub> (sat) | Collector-Emitter Saturation Voltage | $I_C$ =10mA, $I_B$ =1mA<br>$I_C$ =50mA, $I_B$ =5mA   |                | 0.15<br>0.25 | V<br>V |
| V <sub>BE</sub> (sat) | Base-Emitter Saturation Voltage      | $I_C$ =10mA, $I_B$ =1mA<br>$I_C$ =50mA, $I_B$ =5mA   |                | 1.0<br>1.2   | V<br>V |
| f <sub>T</sub>        | Current Gain Bandwidth Product       | I <sub>C</sub> =10mA, V <sub>CE</sub> =10V 10<br>f=100MHz                                  |                | 300          | MHz    |
| C <sub>ob</sub>       | Output Capacitance                   | V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1.0MHz  |                | 6.0          | pF     |



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# **Typical Characteristics**

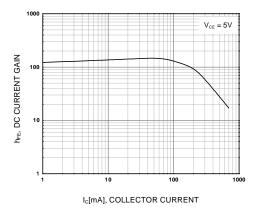


Figure 1. DC current Gain

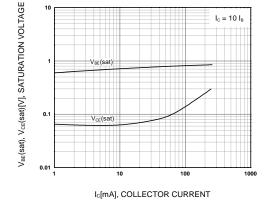


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

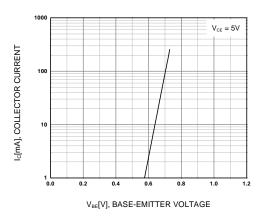


Figure 3. Base-Emitter On Voltage

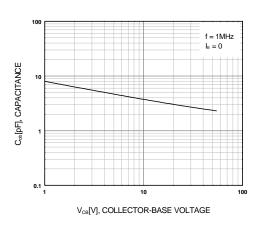


Figure 4. Output Capacitance

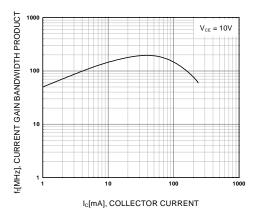
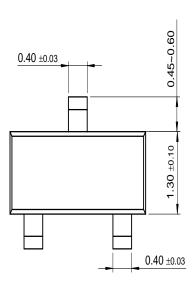
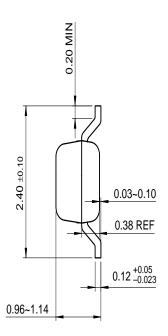


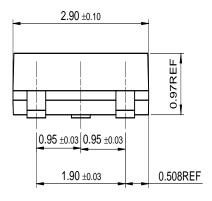
Figure 5. Current Gain Bandwidth Product

# **Package Dimensions**

# **SOT-23**







Dimensions in Millimeters

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